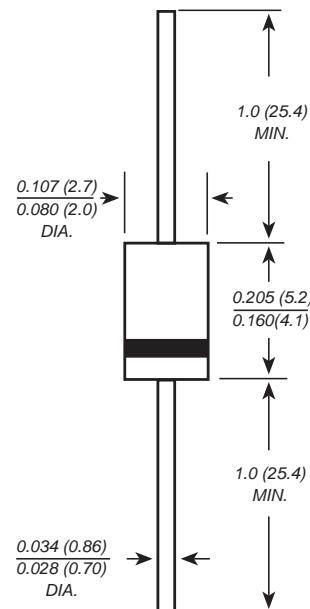




SCHOTTKY BARRIER RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction,majority carrier conduction
- ◆ Low power loss,high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250°C/10 seconds,0.375"(9.5mm) lead length, 5 lbs. (2.3kg) tension

DO-41**Mechanical Data****Case :** JEDEC DO-41 Molded plastic body**Terminals :** Solder plated, solderable per MIL-STD-750, Method 2026**Polarity :** Color band denotes cathode end**Mounting Position :** Any**Weight :** 0.012 ounce, 0.33 grams

Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

Parameter	SYMBOLS	SR 120	SR 130	SR 140	SR 150	SR 160	SR 170	SR 180	SR 190	SR 1100	SR 1150	SR 1200	UNITS		
Marking Code		MDD SR 120	MDD SR 130	MDD SR 140	MDD SR 150	MDD SR 160	MDD SR 170	MDD SR 180	MDD SR 190	MDD SR 1100	MDD SR 1150	MDD SR 1200			
Maximum repetitive peak reverse voltage	V _{RPM}	20	30	40	50	60	70	80	90	100	150	200	V		
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	49	56	63	70	105	140	V		
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	70	80	90	100	150	200	V		
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I _(AV)	1.0										A			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	40										A			
Maximum instantaneous forward voltage at 1.0A	V _F	0.55		0.70		0.85			0.95		V				
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.5					0.2			2.0		mA			
Typical junction capacitance (NOTE 1)	C _J	110		80			50.0			50.0		pF			
Typical thermal resistance (NOTE 2)	R _{θJA}	50.0										°C/W			
Operating junction and storage	T _J	-50 to +125				-50 to +150				150		°C			
Storage temperature range	T _{STG}	-50 to +150										°C			

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length,P.C.B. mounted



Ratings And Characteristic Curves

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE

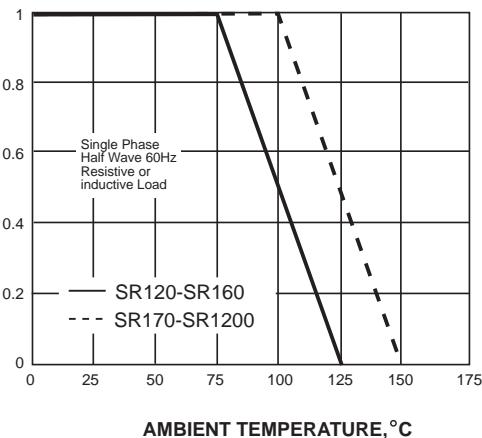
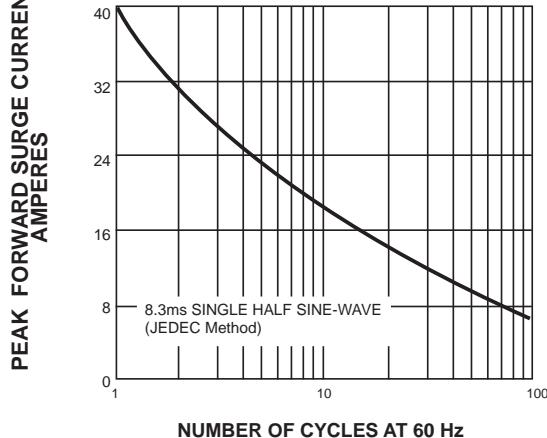
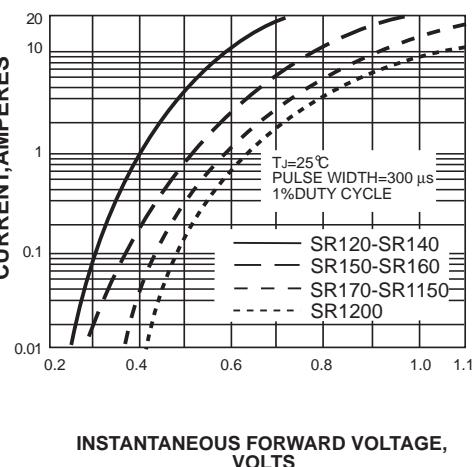


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



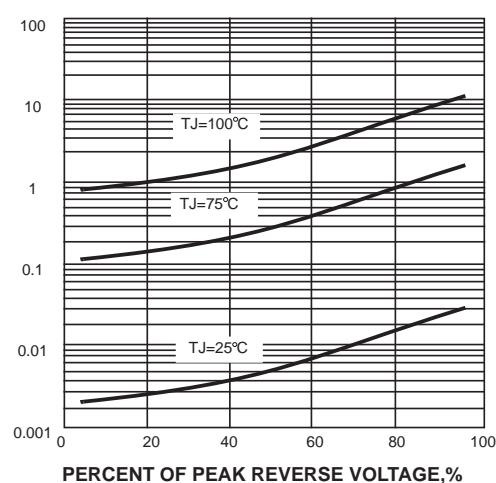
INSTANTANEOUS FORWARD CURRENT,AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



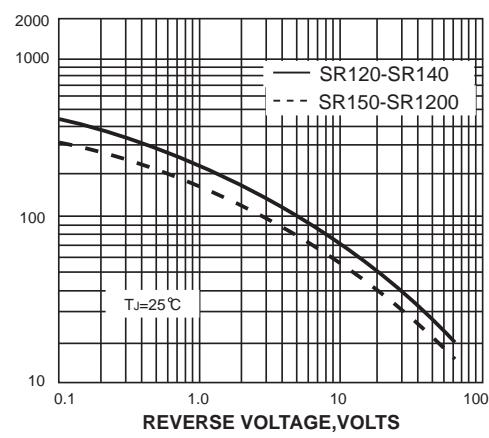
INSTANTANEOUS REVERSE CURRENT,
MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



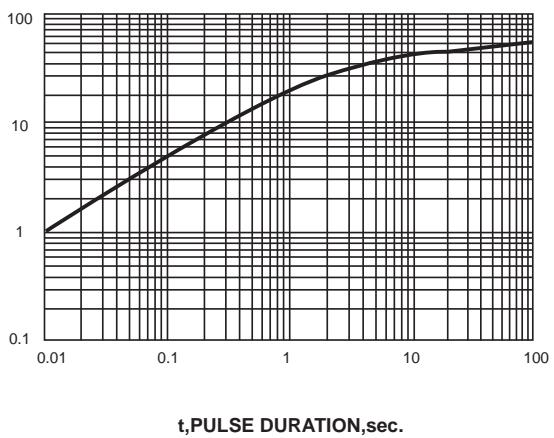
JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The curve above is for reference only.